

Compact LCD Bias IC With High Speed Amplifiers for TV-LCD Panels

FEATURES

- **8-V to 14.4-V Input Voltage Range Soft Start for all Converters**
- **500 kHz / 750 kHz Fixed Switching Frequency Two Integrated High-Speed Opamps**
- **Boost Output Voltage up to 19 V – 50-MHz, 3-dB Bandwidth**
	- **– 1%-Accurate Boost With 2.8-A Switch – Slew Rate 55 V /** µ**s Current Overvoltage Protection – 215-mA Short-Circuit Current**
- **Input-to-Output Isolation Switch for Vs 48 Pin 7x7 mm QFN Package Short-Circuit protection for Boost**
- **2.5-A Step-Down Converter**
- **Regulated Positive Charge-Pump Driver VGH LCD TV**
- **Regulated Negative Charge-Pump Driver VGL LCD Monitor**
- **Gate Voltage Shaping for VGH**
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APPLICATIONS

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DESCRIPTION

The TPS65162 is a compact LCD bias IC with two high-speed operational amplifiers for the $V_{\rm com}$ supply. The high current capability of the device is ideal for large LCD-monitor and LCD-TV applications.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

DESCRIPTION (CONTINUED)

The TPS65162 generates all four voltage rails for a TFT LCD (Vs, Vlogic, VGH and VGL) and includes two op-amps to generate the VCOM supply rail. An input-to-output isolation switch is integrated into the device, providing short-circuit protection for the boost converter. A current-limit function is implemented in the input-to-output isolation switch to allow soft turn-on during start-up. The device also features gate voltage shaping for improved TFT-LCD picture quality. The device consists of a boost converter to provide the source voltage Vs, and a step-down converter to provide the logic voltage for the system. A positive and a negative charge-pump driver provide adjustable regulated output voltages VGH and VGL to bias the TFT. Both boost and buck converter, as well as the charge-pump drivers, operate with a fixed switching frequency of 500 kHz or 750 kHz, selectable by the FREQ pin. The device includes adjustable power-on sequencing. The safety features of the device are overvoltage protection for boost converter, short-circuit protection for Vs, Vlogic and VGH, and thermal shutdown.

ORDERING INFORMATION(1)

(1) The RGZ package is available taped and reeled and shipped in quantities of 2500 devices per reel.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

DISSIPATION RATINGS(1)

(1) Exposed thermal die is soldered to the PCB using thermal vias. Refer to Texas Instruments Application report [\(SLUA271](http://www-s.ti.com/sc/techlit/SLUA271)) QFN/SON PCB Attachment.

RECOMMENDED OPERATING CONDITIONS

ELECTRICAL CHARACTERISTICS

Vin=12 V, EN1=EN2=FREQ=high, Vs=15 V, Vlogic=3.3 V , T_A = -40°C to 85°C, typical values are at T_A = 25°C (unless otherwise noted)

ELECTRICAL CHARACTERISTICS (continued)

Vin=12 V, EN1=EN2=FREQ=high, Vs=15 V, Vlogic=3.3 V ,T_A = –40°C to 85°C, typical values are at T_A = 25°C (unless otherwise noted)

(1) The maximum charge pump output current is typically one-half the drive current of the internal current source.

NOTE: The thermally-enhanced PowerPAD is connected to PGND1 (Device power Ground). NC pin is internally not connected.

TERMINAL FUNCTIONS

TERMINAL FUNCTIONS (continued)

L1
10 μ H D₁ Vin the contract of 10μ H 8 V to 14 V Vs 15 V/1.5 A C11 C12
1 μ F C9 $C10$ $\frac{1}{\sqrt{1}}$ $\begin{array}{ccc} \text{R1} & \text{C7} \\ \text{R20 pF} \end{array}$ $\begin{array}{ccc} \text{C8} \\ \text{C9} \end{array}$ C2 22 mF C1 22 mF ՝ C5
10 μF 1μ F $\frac{1}{2}$ C7
220 pF $\frac{10}{22}$ µF 22 μF | 22 μF \mathbb{R} \top \top ∔ Ť R2
3.6 kΩ . C4
22 μF PVIN PVIN AVIN ်
| D2D3 SW SW SWO SUP
FB $\frac{1}{2}$ switched $\frac{1}{2}$ sw $EN1 \begin{array}{ccc} \downarrow \downarrow & \downarrow \downarrow \\ \downarrow \downarrow & \downarrow \downarrow \end{array}$ $\begin{array}{ccc} & & & \circ & \searrow & \cdot \\ & & & \circ & \searrow \\ & & & \downarrow \end{array}$ 获取更多资料 微信搜索蓝领星球EN2 **Boost** Converter DRVP FREQ J_D $\begin{array}{ccc} \n\searrow & & \perp & \n\searrow & & \searrow & & \searrow & \n\searrow &$ C16
470 nF $\mathbb{F}_\mathbf{s}$ R5 VGH $T_{470 \text{ nF}}$ $\begin{array}{c} + \ + \ \end{array}$ VIN $62 k\Omega$ FBP $1 \mu F$ $\frac{1}{C_1}$ SS R6
3.3 kΩ VGHM Gate Voltage 22 nF $\frac{1}{C_1}$ VC O VGH Shaping 25 V/50 mA CE RE 22 nF Vs $\frac{1}{C14}$ W_{R10} R7
10 KΩ 100 pF $1 KQ$ Enable Gate VDPM VDD Voltage shaping VFLK CBOOT R8
1.5 KΩ VFLK O \perp c20 D4D5 SWB **Buck** VGL 100 nF DRVN $-5V/50$ mA \circ **Converter** SWB C18 D SVlogic L2 3.3 V/2.5 A 470 nF C7
470 nF R3
200 kΩ $\frac{470}{10}$ nF $\frac{1}{10}$ $\frac{1}{1$ FBB $2.4 \text{ k}\Omega$ 470 pF 22μ F 22μ F FBN D5 REF R4
51 kΩ DLY1 $C24$ R12
1.5 kΩ $\frac{+}{}$ _{C19} AGND 10 nF DLY2 $\overline{2}$ $\overline{C25}$ 1 220 nF PGND2 PGND3 OGND PGND1 NEG2 22 nF NEG1 OUT2 GND OUT1 POS1

FUNCTIONAL BLOCK DIAGRAM

TYPICAL CHARACTERISTICS

Table of Graphs

BOOST CONVERTER (Vs)

8 Submit [Documentation](http://www.go-dsp.com/forms/techdoc/doc_feedback.htm?litnum=SLVS771&partnum=TPS65162) Feedback

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[TPS65162](http://focus.ti.com/docs/prod/folders/print/tps65162.html)

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SYSTEM PERFORMANCE

NEGATIVE CHARGE PUMP DRIVER

VCOM BUFFERS

APPLICATION INFORMATION

THERMAL SHUTDOWN

The thermal-shutdown feature prevents damage from excessive heat and power dissipation. Typically, the thermal-shutdown threshold is 160°C. When the temperature drops below the thermal shutdown threshold, the device restarts again automatically.

UNDERVOLTAGE LOCKOUT

To avoid device malfunction at low input voltages, an undervoltage lockout is included, which shuts down the device at voltages lower than 7.6 V.

REFERENCE OUTPUT, REF

The device provides a reference output that is used to regulate the negative charge pump. In order to have a stable reference voltage, a 220-nF bypass capacitor is required, connected directly from REF to AGND. The reference output has a current capability of 30 µA which should not be exceeded. Because of this, the feedback resistor from FBN to REF should not be smaller than 40 kΩ.

START-UP SEQUENCING

The start-up sequencing can be set by adjusting the capacitors connected to DLY1 and DLY2, and is controlled by the signals EN1 and EN2. Pulling EN1 high enables the step-down converter. After the step down converter has reached its power-good threshold, the other sequence timings are started. DLY1 sets the delay time between the step-down converter and the negative charge-pump driver. This delay starts when the power-good threshold of the step-down converter is reached. A high level on EN2 enables the boost converter. The boost converter starts when the power-good threshold of the step down converter is reached and EN2 is pulled high. DLY2 sets the delay time for the positive charge pump. This delay time starts when the power good threshold of the step down converter is reached. After the delay time has expired, the positive charge pump and op-amps start up. As the positive charge pump power-good threshold is reached, then the GPM block is enabled if VDPM is high as well. See Figure 19.

Figure 19. Power-On Sequencing With EN2 Always High (EN2=VIN)

APPLICATION INFORMATION (continued)

If EN2 goes high after the step down converter is already enabled, then the delay DLY2 starts when EN2 goes high. See Figure 20.

SETTING THE DELAY TIMES DLY1, DLY2

Connecting an external capacitor to the DLY1 and DLY2 pin sets the delay time. If no delay time is required these pins can be left open. To set the delay time the external capacitor connected to DLY1 and DLY2 is charged with a constant current source of typically 5 µA. The delay time is terminated when the capacitor voltage has reached the internal reference voltage of $V_{REF}=1.280$ V. The external delay capacitor is calculated using Equation 1:

$$
C_{\text{dly}} = \frac{5\,\mu\text{A} \times t_{\text{d}}}{V_{\text{REF}}} = \frac{5\,\mu\text{A} \times t_{\text{d}}}{1.280\,\text{V}}
$$

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where t_d = Desired delay time

Example for setting a delay time of 5.3 ms:

$$
C_{\text{dly}} = \frac{5 \mu A \times 5.3 \text{ ms}}{1.280 \text{ V}} = 20.7 \text{ nF} \approx 22 \text{ nF}
$$

(2)

(1)

APPLICATION INFORMATION (continued)

BOOST CONVERTER

The TPS65162 boost converter block is shown in Figure 21. The boost converter operates with PWM (Pulse Width Modulation) at a fixed switching frequency of 500 kHz or 750 kHz, selected by the FREQ pin. The converter uses an unique fast-response, voltage-mode controller scheme with input-voltage feedforward. This achieves excellent line and load regulation (0.03%/A load regulation typical), and allows the use of small external components. To add more flexibility to the selection of external component values, the device uses external loop compensation. Although the boost converter looks like a non-synchronous boost converter topology operating in discontinuous-conduction mode under a light load, the TPS65162 remains in continuous-conduction mode even under light load currents. [\(Figure](#page-8-0) 4) This is achieved with a novel architecture using an external Schottky diode with an integrated MOSFET in parallel connected between the SW pin and the SUP pin. This MOSFET allows the current to go below ground, which is the case under light load conditions. For this use, a small integrated P-Channel MOSFET (Q2) with typically 9 Ω RDSon is sufficient. When the inductor current is positive, the external Schottky diode, with the lower forward voltage, carries the current. This causes the converter to operate with a fixed frequency in continuous-conduction mode over the entire load-current range. This avoids ringing on the switch pin as seen with a standard non-synchronous boost converter, and allows a simpler compensation circuit for the boost converter.

Figure 21. Boost Converter Block TPS65162

APPLICATION INFORMATION (continued)

Soft Start

To minimize inrush current during startup, the boost converter has an adjustable soft-start, and the input-to-output isolation switch has current-limit control. The current limit of the input-to-output isolation switch is slowly ramped up for a soft turn-on. The VDS sensor of the input-to-output isolation switch monitors the voltage difference between SWI and SWO, and controls the current through the isolation switch. With VDS = 12 V, the current-limit threshold through the isolation switch is typically 330 mA. This current-limit threshold will linearly increase by factor of two till VDS reaches 3 V; current limiting is disabled when VDS is below 3 V. The boost converter is enabled when VDS is below 0.5 V. An external capacitor connected to the soft-start pin, SS, is used to slowly ramp up the internal switch current limit of the boost converter. The capacitor connected to the SS pin is charged with a constant current that increases the voltage on the SS pin. The internal current limit is proportional to the voltage on the SS pin. When the threshold voltage of the internal-switch soft-start comparator is reached, the full current limit is released. The larger the soft-start capacitor value, the longer the soft-start time. A 22-nF capacitor is usually sufficient for typical applications.

Overvoltage Protection

The boost converter has an overvoltage-protection circuit to prevent the switch voltage from exceeding the absolute-maximum switch voltage rating in the event of a system fault. The device protects itself if the feedback pin is connected to ground or floated, and clamps the voltage of the output of the boost converter to 20 V. To implement the overvoltage protection, the overvoltage comparator shown in Figure 21 monitors the output voltage via the SWI pin. As soon as the output voltage exceeds the overvoltage threshold (typically 20 V), the device stops switching until the output voltage drops below the comparator threshold again. The typical waveform when the device is in overvoltage protection is shown in Figure 7. With a constant current that increases the evologie on the SS pin. The internal current that is the information and current that increases the constant current that increases the constant current internal current limit i

Short CIrcuit Protection

The boost converter has a short-circuit protection circuit to prevent the inductor or rectifier diode from overheating when the output is shorted. The VDS sensor in the input-to-output isolation switch monitors the voltage difference between SWI and SWO. If the boost output is shorted, and the voltage difference between SWI and SWO exceeds the threshold (typically 1.4 V in full operation), then the boost converter shuts down, and the input-to-output isolation switch limits VS current.

Input Capacitor Selection (VIN, SUP)

Low ESR ceramic capacitors are recommended for good input-voltage filtering. The TPS65162 has an analog input (VIN) as well as a power supply input (SUP) powering all the internal rails. A 1-µF bypass capacitor is required as close as possible from VIN to GND, and from SUP to GND. Depending on the overall load current, two or three 22-µF input capacitors are required. For better input-voltage filtering, the input capacitor values can be increased. Refer to Table 1 and the Typical Applications schematic for input capacitor recommendations.

CAPACITOR	COMPONENT SUPPLIER	COMMENTS
$22 \mu F / 16 V$	Taiyo Yuden EMK316BJ226ML	Pin VIN, PVIN
$2 \times 10 \text{ µF}$ / 25 V	Taiyo Yuden TMK316BJ106KL	Pin VIN, PVIN (Alternative)
$1 \mu F / 35 V$	Taiyo Yuden GMK107BJ105KA	Pin SUP, AVIN, VIN
1 µF / 25 V	Taiyo Yuden TMK107BJ105KA	Pin SUP, AVIN, VIN

Table 1. Input Capacitor Selection

Frequency Select Pin, FREQ

The frequency-select pin FREQ selects the switching frequency of the entire device to 500 kHz (FREQ=low) or 750 kHz (FREQ=high). A lower switching frequency gives a higher efficiency with a slightly reduced load-transient regulation.

Boost Converter Design Procedure

The first step in the design procedure is to verify whether the maximum possible output current of the boost converter supports the specific application requirements. To simplify the calculation, the fastest approach is to estimate the converter efficiency, by taking the efficiency numbers from the provided efficiency curves, or to use a worst-case assumption for the expected efficiency, e.g., 80%. With the efficiency number it is possible to calculate the steady-state values of the application.

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- $D = 1 \frac{V \cdot \text{ln} \times \eta}{V \cdot \text{ln} \cdot \text{ln}}$ Vout 1. Converter Duty Cycle:
- 2. Maximum output current:

$$
Iout = \left(Isw - \frac{Vin \times D}{2 \times fs \times L} \right) \times (1 - D)
$$

3. Peak switch current:

$$
I_{\text{swpeak}} = \frac{\text{Vin} \times D}{2 \times f s \times L} + \frac{I_{\text{out}}}{1 - D}
$$

With Isw = converter switch current (minimum switch current limit = 2.8 A)

- $fs =$ converter switching frequency (typical 500kHz or 750 kHz)
- $L =$ Selected inductor value
- η = Estimated converter efficiency (use the number from the efficiency curves or 0.8 as an estimation)

The peak switch current is the steady-state peak switch current that the integrated switch, inductor and external Schottky diode must be able to handle. The calculation must be done for the minimum input voltage where the peak switch current is highest.

Inductor Selection

The TPS65162 typically operates with a 10-µH inductor. The main parameter for inductor selection is the inductor saturation current, which should be higher than the peak switch current, as calculated above, with additional margin to handle heavy load transients. An alternative more conservative approach is to choose an inductor with a saturation current at least as high as the typical switch current limit of 3.6 A. The second important parameter is the inductor DC resistance. Usually, the lower the DC resistance, the higher the efficiency of the converter. The choice of inductor can affect converter efficiency by as much as 10%. Example inductors are shown in Table 2. Im output current: $\left.\frac{\text{Out}}{\text{low-peak}} = \frac{\text{Vi}_{\text{II}} \times \text{D}}{\text{2} \times f \text{s} \times \text{L}} + \frac{1}{1 - \text{D}}$

witch current: $\left.\frac{\text{J}_{\text{group-peak}} = \frac{\text{Vi}_{\text{II}} \times \text{D}}{\text{2} \times f \text{s} \times \text{L}} + \frac{1}{1 - \text{D}}}{1 - \text{D}}\right.$

switch current switching frequen

Table 2. Inductor Selection (Boost Converter)

Output Capacitor

For best output-voltage filtering, a low-ESR output capacitor is recommended. Ceramic capacitors have a low ESR value and work best with the TPS65162. One 10-µF ceramic output capacitor before the input-to-output isolation switch, SWI, and six 10-µF or three 22-µF ceramic output capacitors in parallel after the input-to-output isolation switch, SWO, are sufficient for most applications. To improve the load transient regulation, add more capacitors after the input-to-output isolation switch. Refer to Table 3 for the selection of the output capacitor.

To achieve high efficiency, a Schottky diode should be used. The reverse voltage rating should be higher than the maximum output voltage of the converter. The current rating for the Schottky diode is calculated as the off time of the converter times the typical switch current of the TPS65162:

$$
I_{avg} = (1 - D) \cdot I_{SW} = \frac{V_{in}}{V_{out}} \times 3.6 \text{ A}
$$

where I_{SW} =typical switch current of the TPS65162 (3.6 A)

A Schottky diode with 2-A maximum average rectified forward current rating is sufficient for most applications. The Schottky rectifier must have adequate power dissipation. The dissipated power is the average rectified forward current times the diode forward voltage.

$$
P_D = I_{avg} \cdot V_F = I_{SW} \cdot (1 - D) \cdot V_F
$$

where $I_{SW}=$ typical switch current of the TPS65162 (3.6 A)

Table 4. Rectifier Diode Selection (Boost Converter)

Setting the Output Voltage and Selecting the Feedforward Capacitor

The output voltage is set by the external resistor divider and is calculated as:

$$
V_{\text{out}} = 1.268 \text{ V} \times \left(1 + \frac{R1}{R2}\right)
$$

Across the upper resistor a bypass capacitor is required to speed up the circuit during load transients. The capacitor is caluculated as:

$$
C_{ff} = \frac{1}{2 \cdot \pi \cdot f_z \cdot R1}
$$
 (6)

Depending on the inductor value, the zero frequency needs to be set. f_z is 19 kHz for a 10 µH inductor, and 9 kHz for a 22 µH inductor. A value coming closest to the calculated value should be used.

Compensation (VC)

The regulator loop can be compensated by adjusting the external components connected to the VC pin. The VC pin is the output of the internal transconductance error amplifier. A single capacitor connected to this pin sets the low frequency gain. A 22-nF capacitor is usually sufficient for most applications.

(3)

(4)

(5)

POSITIVE CHARGE PUMP

The positive charge pump provides a regulated output voltage set by the external resistor divider. The TPS65162 positive charge pump block is shown in Figure 22.

Figure 22. Positive Charge Pump Block TPS65162

Since the flying capacitor-voltage sits on top of the drive-pin voltage, the maximum output voltage is $V_{SUP}+V_S \rm V_{drop}$. $\rm V_{drop}$ is the voltage drop across the external diodes and internal charge pump MOSFETs. If higher output voltages are required, another charge pump stage can be added to the output.

Setting the output voltage:

$$
V_{\text{out}} = V_{\text{REF}} \times \left(1 + \frac{\text{R5}}{\text{R6}}\right) = 1.265 \text{ V} \times \left(1 + \frac{\text{R5}}{\text{R6}}\right) \tag{7}
$$

To minimize noise and leakage current sensitivity, we recommend a value of approximately 20 kΩ for the lower feedback divider resistor R6.

NEGATIVE CHARGE PUMP

The negative charge pump provides a regulated output voltage set by the external resistor divider. The TPS65162 negative charge pump block is shown in Figure 23. The negative charge pump operates very similar to the positive charge pump, with the difference that it runs from the input voltage VIN. The maximum negative output voltage is $VGL=(-VIN)+V_{drop}$. V_{drop} is the voltage drop across the external diodes and internal charge-pump MOSFETs.

The output voltage is calculated by:

$$
V_{\text{out}} = -V_{\text{REF}} \times \frac{\text{R3}}{\text{R4}} = -1.265 \text{ V} \times \frac{\text{R3}}{\text{R4}}
$$
(8)

Since the reference-output driver current should not exceed 30uA (typical), the lower feedback resistor value R4 should be in a range of 40 kΩ to 120 kΩ. Overall feedback resistance should be in the range from 500 kΩ to 1 MΩ. The negative charge pump requires two external Schottky diodes. The peak current rating of the Schottky diode must be twice the load current of the output. For a 20-mA output current, the dual Schottky diode BAV99 is a good choice.

Figure 23. Negative Charge Pump Block TPS65162

GATE VOLTAGE SHAPING

The gate voltage shaping reduces the flickering effect of an LCD panel, and isolates VGHM from the source voltage VGH. For correct operation of this block, it is not recommend to connect an output capacitor to VGHM. To reduce the voltage ripple on VGHM, add more capacitors on VGH. The TPS65162 gate voltage shaping block is shown in [Figure](#page-21-0) 24. The corresponding timing diagram is shown in Figure 26. The gate voltage shaping block responds to VFLK under the following conditions:

- The device is enabled with $VDPM = high$
- The input voltage is above the undervoltage lockout
- The positive charge pump is in regulation

When VGH is pulled below its power-good level, Q1 and Q2 are turned off and VGHM is discharged via the 1-kΩ resistor over Q3. With VFLK = high, Q1 and Q4 are turned on and Q2 is turned off. VGH is present at VGHM when Q1 is on, and at the same time, the capacitor connected to the CE pin is discharged by Q4 to

GND. When VFLK is taken low, Q4 is turned off, and the capacitor connected to the CE pin is charged by a constant current source, typically 60 µA. When the capacitor voltage reaches the internal reference voltage of 1.284 V and VFLK is low, Q1 is turned off and Q2 is turned on. With Q2 on, VGHM is discharged by the resistor connected to the RE pin. Once VGHM is discharged to five times VDD, Q2 is turned off and VGHM is high impedance. In the application of not using this function, connect VDPM, VFLK with high.

Figure 24. Gate Voltage Shaping Block TPS65162

Figure 25. Gate Voltage Shaping Block TPS65162

STEP-DOWN CONVERTER

The TPS65162 step down converter block is shown in Figure 26. The non-synchronous step down converter operates at a fixed switching frequency using a fast response voltage mode topology with input voltage feedforward. This topology allows simple internal compensation and it is designed to operate with ceramic output capacitors. The converter drives an internal 2.8 A N-Channel MOSFET switch. The MOSFET driver is referenced to the switch pin SWB. The N-Channel MOSFET requires a gate drive voltage higher than the switch pin to turn the N-Channel MOSFET on. This is accomplished by a boost strap gate drive circuit running of the step down converter switch pin. When the switch pin SWB is at ground the boot strap capacitor is charged to 8 V. This way the N-Channel Gate drive voltage is typically around 8 V.

Soft Start

To avoid high inrush current during startup, an internal soft-start is implemented. When the step down converter is enabled over EN1, its reference voltage slowly rises from zero to its power good threshold of typically 90% of Vref. When the reference voltage reaches this power good threshold, the Error amplifier is released to its normal operation with its normal duty cycle. To further limit the inrush current during soft-start the converter frequency is set to 1/4 of the switching frequency fs and 1/2 of fs by the comparator that monitors the feedback voltage. refer to the internal block diagram. The typical soft-start is typically completed within 1ms.

Short Circuit Protection

To limit the short circuit current, the device has a cycle-by-cycle current limit. To prevent the short-circuit current from rising above the internal current limit when the output is shorted to GND, the switching frequency is reduced as well. This is implemented by two comparators monitoring the feedback voltage. The step-down converter switching frequency is reduced to 1/2 of ƒfs when the feedback is below 0.9 V, and 1/4 of the switching frequency when the feedback voltage is below 0.6 V.

Figure 26. Step Down Converter Block TPS65162

[TPS65162](http://focus.ti.com/docs/prod/folders/print/tps65162.html)

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Setting the Output Voltage

The step-down converter uses an external voltage divider to set the output voltage. The output voltage is calculated as:

$$
V_{\text{out}} = 1.265 \text{ V} \times \left(1 + \frac{\text{R5}}{\text{R6}}\right) \tag{9}
$$

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At load currents <1 mA, the device operates in discontinuous conduction mode. When the load current is reduced to zero the output voltage rises slightly above the nominal output voltage. At zero load current, the device skips clock cycles, but does not completely stop switching, thus the output voltage sits slightly above the nominal output voltage. Therefore, the lower feedback resistor is selected to be around 1.2 kΩ to maintain around 1 mA minimum load current.

Selecting the Feedforward Capacitor

The feedforward capacitor across the upper feedback resistor divider forms a zero around 135 kHz, and is calculated as:

$$
C_{z} = \frac{1}{2 \times \pi \times 135 \text{kHz} \times \text{R5}} = \frac{1}{2 \times \pi \times 135 \text{kHz} \times 2.5 \text{k}\Omega} = 471.6 \text{ pF} \approx 470 \text{ pF}
$$
(10)

Usually the standard capacitor value closest to the calculated value is selected.

Inductor Selection

The TPS65162 step-down converter typically operates with a 10-µH inductor. For high efficiency, the inductor should have a low DC resistance to minimize conduction loss. This must be considered when selecting the appropriate inductor. In order to avoid inductor saturation, the inductor should be rated at least for the maximum output current of the converter plus the inductor ripple current that will be calculated by:

$$
\Delta I_{L} = \text{Vout} \times \frac{1 - \frac{\text{Vout}}{\text{Vin}}}{L \times f} \qquad I_{Lmax} = I_{\text{outmax}} + \frac{\Delta I_{L}}{2}
$$
\n(11)

where

 f = Switching Frequency (750 kHz, 500 kHz minimal)

L = Inductor Value (typically 10 μ H)

 ΔI_1 = Peak to Peak inductor ripple current

 I_{Lmax} = Maximum Inductor current

The highest inductor current occurs at maximum Vin. A more conservative approach is to select the inductor current rating just for the typical switch-current limit of 3.5 A.

Table 5. Inductor Selection

Rectifier Diode Selection

To achieve high efficiency, a Schottky diode should be used. The reverse voltage rating should be higher than the maximum output voltage of the step-down converter. The averaged rectified forward current for which the Schottky diode should be rated is calculated as the off time of the step-down converter times the minimum switch current of the TPS65162:

$$
D = \frac{V_{OUT}}{V_{IN}}
$$
 (12)

$$
I_{avg} = (1 - D) \cdot I_{SW} = (1 - \frac{V_{OUT}}{V_{IN}}) \cdot 2.8 \text{ A}
$$
\n(13)

where Isw = minimum switch current of the TPS65162 (2.8 A)

Usually a Schottky diode with 2 A maximum average rectified forward current rating is sufficient for most of the applications. Secondly the Schottky rectifier has to be able to dissipate the power. The dissipated power is the average rectified forward current times the diode forward voltage.
 $P_P = \log_2 X V_P = \log_2 X (1 - D) \times V_P$

$$
P_{D} = I_{avg} \times V_{F} = \text{Isw} \times (1 - D) \times V_{F}
$$
 with $I_{SW} = \text{minimum switch current of the TPS65162 (2.8 A)}$

Table 6. Rectifier Diode Selection (Step-Down Converter)

Output Capacitor Selection

The device is designed to work with ceramic output capacitors. Two 22-µF output capacitors are sufficient for most of the applications. Larger output capacitance improves the load transient response.

OPERATIONAL AMPLIFIER 1 AND 2

The TPS65162 has two integrated operational amplifiers. The operational amplifiers can be used as a gamma-correction buffer or as a VCOM buffer.

Figure 27. Operational Amplifier Block TPS65162

The power supply pin for the opamps is the AVIN pin connected to the boost converter Vs. To achieve good performance and minimize the output noise, a 1-µF bypass capacitor is required directly from the AVIN pin to ground. The opamps are not designed to drive capacitive loads, therefore it is not recommended to connect a capacitor directly to the output of the opamps. If capacitive loads are driven, use a series resistor at the output to provide stable operation. With a 3.3-Ω series resistor, a capacitive load of 10 nF can be driven, which is usually sufficient for typical LCD applications.

Operational Amplifier Termination

For some applications, not all of the amplifiers are used. To minimize device quiescent current the terminals should be terminated. The negative terminal is connected to the output of the operational amplifier and positive terminal is connected to GND and the output is left open. This termination minimizes device quiescent current and maintains correct functionality of the device.

PCB LAYOUT DESIGN GUIDELINES

- 1. Place the power components outlined in bold first on the PCB.
- 2. Rout the traces outlined in bold with wide PCB traces.
- 3. Place a 1-µF bypass capacitor directly from the SUP pin to GND and from AVIN to GND.

- 4. Use a short and wide trace to connect the SUP pin to the output of the boost converter Vs.
- 5. Place the 220-nF reference capacitor directly from REF to GND close to the IC pins.
- 6. The feedback resistor for the negative charge pump between FBN and REF should be >40 kΩ.
- 7. Use short traces for the charge-pump drive pin (DRVN) of VGL because the traces carry switching waveforms.
- 8. Solder the PowerPad™ of the QFN package to GND, and use thermal vias to lower the thermal resistance.
- 9. For more layout recommendations, refer to the TPS65162 evaluation module (EVM)

Figure 28. PCB Layout Recommendation TPS65162

TYPICAL APPLICATION

MECHANICAL DATA

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-leads (QFN) package configuration.

⚠ The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.

E. Falls within JEDEC MO-220.

THERMAL PAD MECHANICAL DATA

RGZ (S-PQFP-N48)

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to a ground or power plane (whichever is applicable), or alternatively, a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, Quad Flatpack No-Lead Logic Packages, Texas Instruments Literature No. SCBA017. This document is available

TAPE AND REEL INFORMATION

PACKAGE MATERIALS INFORMATION WEXAS
INSTRUMENTS
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TAPE AND REEL BOX INFORMATION

MECHANICAL DATA

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-leads (QFN) package configuration.

⚠ The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.

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For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, Quad Flatpack No-Lead Logic Packages, Texas Instruments Literature No. SCBA017. This document is available

RGZ (S-PQFP-N48)

- NOTES:
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	- Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.
	- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
	- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

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